Data Sheet

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File Number

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Quad, 1MHz, Operational Amplifiers for Commercial, Industrial, and Military **Applications**

The CA124, CA224, CA324, LM324, and LM2902 consist of four independent, high-gain operational amplifiers on a single monolithic substrate. An on-chip capacitor in each of the amplifiers provides frequency compensation for unity gain. These devices are designed specially to operate from either single or dual supplies, and the differential voltage range is equal to the power-supply voltage. Low power drain and an input common-mode voltage range from 0V to V+ -1.5V (single-supply operation) make these devices suitable for battery operation.

Part Number Information

PART NUMBER (BRAND)	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
CA0124E	-55 to 125	14 Ld PDIP	E14.3
CA0124M (124)	-55 to 125	14 Ld SOIC	M14.15
CA0124M96 (124)	-55 to 125	14 Ld SOIC Tape and Reel	M14.15
CA0224E	-40 to 85	14 Ld PDIP	E14.3
CA0224M (224)	-40 to 85	14 Ld SOIC	M14.15
CA0324E	0 to 70	14 Ld PDIP	E14.3
CA0324M (324)	0 to 70	14 Ld SOIC	M14.15
CA0324M96 (324)	0 to 70	14 Ld SOIC Tape and Reel	M14.15
LM324N	0 to 70	14 Ld PDIP	E14.3
LM2902N	-40 to 85	14 Ld PDIP	E14.3
LM2902M (2902)	-40 to 85	14 Ld SOIC	M14.15
LM2902M96 (2902)	-40 to 85	14 Ld SOIC Tape and Reel	M14.15

Features

Operation from Single or Dual Supplies
Unity-Gain Bandwidth
DC Voltage Gain
Input Bias Current
Input Offset Voltage 2mV (Typ)
Input Offset Current
- CA224, CA324, LM324, LM2902 5nA (Typ)
0.4.0.4

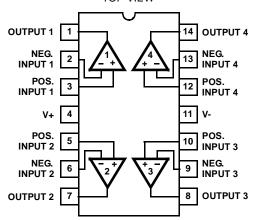
· Replacement for Industry Types 124, 224, 324

Applications

- · Summing Amplifiers
- Multivibrators
- Oscillators
- Transducer Amplifiers
- DC Gain Blocks

Pinout

CA124, CA224, CA324, LM2902 (PDIP, SOIC) LM324 (PDIP) TOP VIEW



CA124, CA224, CA324, LM324, LM2902

Absolute Maximum Ratings

Supply Voltage32V or ±16V
Differential Input Voltage
Input Voltage0.3V to 32V
Input Current (V _I < -0.3V, Note 1)
Output Short Circuit Duration (V+ < 15V. Note 2) Continuous

Operating Conditions

Temperature	Range	
		55°C to 125°C
	12902	
	1324	

Thermal Information

Thermal Resistance (Typical, Note 3)	θ_{JA} (°C/W)
PDIP Package	95
SOIC Package	175
Maximum Junction Temperature (Die)	
Maximum Junction Temperature (Plastic Package)	
Maximum Storage Temperature Range65	
Maximum Lead Temperature (Soldering 10s) (SOIC - Lead Tips Only)	300°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES

- 1. This input current will only exist when the voltage at any of the input leads is driven negative. This current is due to the collector base junction of the input p-n-p transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral n-p-n parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the amplifiers to go to the V+ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This transistor action is not destructive and normal output states will reestablish when the input voltage, which was negative, again returns to a value greater than -0.3V.
- 2. The maximum output current is approximately 40mA independent of the magnitude of V+. Continuous short circuits at V+ > 15V can cause excessive power dissipation and eventual destruction. Short circuits from the output to V+ can cause overheating and eventual destruction of the device
- 3. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications Values Apply for Each Operational Amplifier. Supply Voltage V+ = 5V, V- = 0V, Unless Otherwise Specified

	TEST	TEMP.		CA124		CA224, CA324, LM324			LM2902			
PARAMETER	CONDITIONS	(°C)	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Input Offset		25	-	2	5	-	2	7	-	-	-	mV
Voltage (Note 6)		Full	-	-	7	-	-	9	-	-	10	mV
Average Input Offset Voltage Drift	$R_S = 0\Omega$	Full	-	7	-	-	7	-	-	7	-	μV/ ^o C
Differential Input Voltage (Note 5)		Full	-	-	V+	-	-	V+	-	-	V+	V
Input Common	V+ = 30V	25	0	-	V+ -1.5	0	-	V+ -1.5	-	-	-	V
Mode Voltage Range (Note 5)	V+ = 30V	Full	0	-	V+ -2	0	-	V+ -2	-	-	-	V
range (Note 3)	V+ = 26V	Full	-	-	-	-	-	-	0	-	V+ -2	V
Common Mode Rejection Ratio	DC	25	70	85	-	65	70	-	-	-	-	dB
Power Supply Rejection Ratio	DC	25	65	100	-	65	100	-	-	-	-	dB
Input Bias	I _I + or I _I -	25	-	45	150	-	45	250	-	-	-	nA
Current (Note 4)	I _I + or I _I -	Full	-	-	300	-	-	500	-	40	500	nA
Input Offset	l ₁ + - l ₁ -	25	-	3	30	-	5	50	-	-	-	nA
Current	l ₁ + - l ₁ -	Full	-	-	100	-	-	150	-	45	200	nA
Average Input Offset Current Drift		Full	-	10	-	-	10	-	-	10	-	pA/ ^o C
Large Signal Voltage Gain	$R_L \ge 2k\Omega$, V+ = 15V (For Large V _O Swing)	25	94	100	-	88	100	-	-	-	-	dB
	$R_L \ge 2k\Omega$, V+ = 15V (For Large V _O Swing)	Full	88	-	-	83	-	-	83	-	-	dB

CA124, CA224, CA324, LM324, LM2902

Electrical Specifications

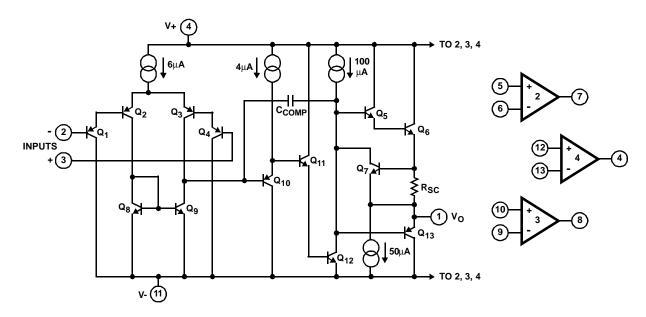
Values Apply for Each Operational Amplifier. Supply Voltage V+ = 5V, V- = 0V, Unless Otherwise Specified (Continued)

TEST PARAMETER CONDITIONS		TEMP.		CA124		CA224	I, CA324,	LM324		LM2902			
		1	(°C)		TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Output		$R_L = 2k\Omega$	25	0	-	V+ -1.5	0	-	V+ -1.5	-	-	-	V
Voltage Swing	High	$R_L = 2k\Omega$, $V + = 30V$	Full	26	-	-	26	-	-	-	-	-	V
June	Level	$R_L = 2k\Omega$, $V + = 26V$	Full	-	-	-	-	-	-	22	-	-	V
		$R_L = 10k\Omega, V + = 30V$	Full	27	28	-	27	28	-	23	28	-	V
	Low Level	$R_L = 10k\Omega$	Full	-	5	20	-	5	20	-	5	100	mV
Output Source Current	Source	V _I + = +1V, V _I - = 0V, V+ = 15V	25	20	40	-	20	40	-	-	-	-	mA
		V _I + = 1V, V _I - = 0, V+ = 15V	Full	10	20	-	10	20	-	10	20	-	mA
	Sink	V _I + = 0V, V _I - = 1V, V+ = 15V	25	10	20	-	10	20	-	-	-	-	mA
		V _I + = 0V, V _I - = 1V, V _O = 200mV	25	12	50	-	12	50	-	-	-	-	μА
		V _I - = 1V, V _I + = 0, V+ = 15V	Full	5	8	-	5	8	-	5	8	-	mA
Crosstall	<	f = 1 to 20kHz (Input Referred)	25	i	-120	-	-	-120	-	-	-	-	dB
Total Su	pply	R _L = ∞	Full	-	0.8	2	-	0.8	2	-	0.7	1.2	mA
Current		R _L = ∞, V+ = 26V	Full	-	-	-	-	-	-	-	1.5	3	mA

NOTES:

- 4. Due to the PNP input stage the direction of the input current is out of the IC. No loading change exists on the input lines because the current is essentially constant, independent of the state of the output.
- 5. The input signal voltage and the input common mode voltage should not be allowed to go negative by more than 0.3V. The positive limit of the common mode voltage range is V+ 1.5V, but either or both inputs can go to +32V without damage.
- 6. $V_O = 1.4V$, $R_S = 0\Omega$ with V+ from 5V to 30V, and over the full input common mode voltage range (0V to V+ 1.5V).

Schematic Diagram (One of Four Operational Amplifiers)



Typical Performance Curves

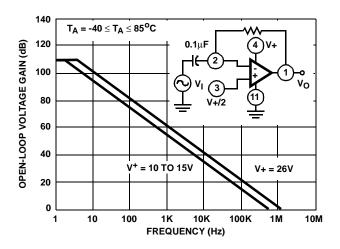


FIGURE 1. OPEN LOOP FREQUENCY RESPONSE

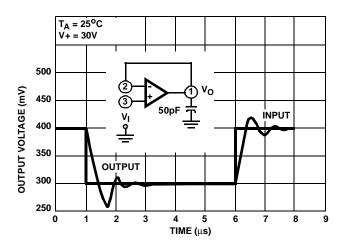


FIGURE 2. VOLTAGE FOLLOWER PULSE RESPONSE (SMALL SIGNAL)

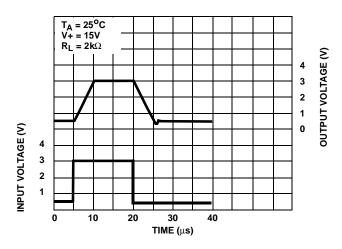


FIGURE 3. VOLTAGE FOLLOWER PULSE RESPONSE (LARGE SIGNAL)

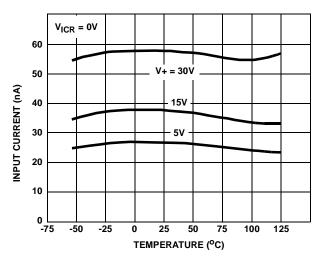


FIGURE 4. INPUT CURRENT vs AMBIENT TEMPERATURE

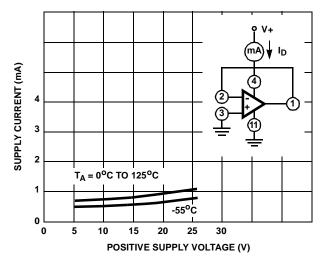


FIGURE 5. SUPPLY CURRENT vs SUPPLY VOLTAGE

Typical Performance Curves (Continued)

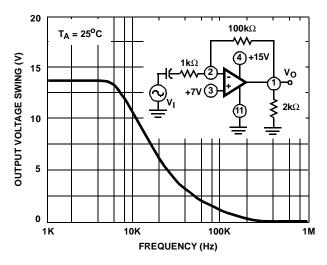


FIGURE 6. LARGE SIGNAL FREQUENCY RESPONSE

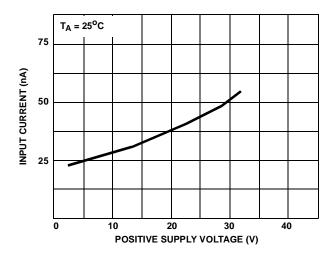


FIGURE 8. INPUT CURRENT vs SUPPLY VOLTAGE

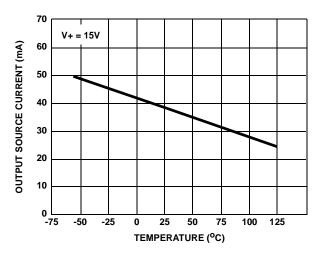


FIGURE 7. OUTPUT CURRENT vs AMBIENT TEMPERATURE

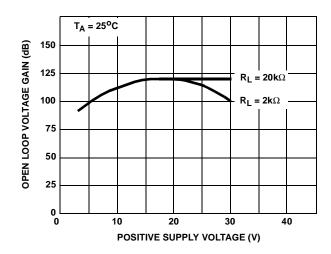
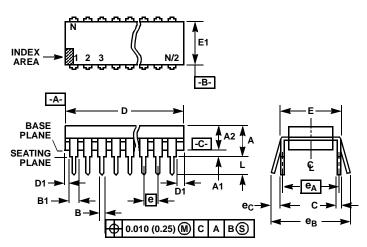


FIGURE 9. VOLTAGE GAIN vs SUPPLY VOLTAGE

Dual-In-Line Plastic Packages (PDIP)



NOTES:

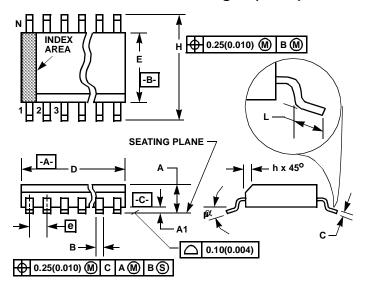
- Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- 3. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
- 4. Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
- D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
- 6. E and e_A are measured with the leads constrained to be perpendicular to datum -C-.
- 7. e_B and e_C are measured at the lead tips with the leads unconstrained. e_C must be zero or greater.
- 8. B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
- 9. N is the maximum number of terminal positions.
- Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

E14.3 (JEDEC MS-001-AA ISSUE D)
14 LEAD DUAL-IN-LINE PLASTIC PACKAGE

	INC	HES	MILLIM		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
Α	-	0.210	-	5.33	4
A1	0.015	-	0.39	-	4
A2	0.115	0.195	2.93	4.95	-
В	0.014	0.022	0.356	0.558	-
B1	0.045	0.070	1.15	1.77	8
С	0.008	0.014	0.204	0.355	-
D	0.735	0.775	18.66	19.68	5
D1	0.005	-	0.13	-	5
Е	0.300	0.325	7.62	8.25	6
E1	0.240	0.280	6.10	7.11	5
е	0.100	BSC	2.54	2.54 BSC	
e _A	0.300	BSC	7.62	6	
e _B	-	0.430	-	10.92	7
L	0.115	0.150	2.93	3.81	4
N	1	4	1	9	

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Small Outline Plastic Packages (SOIC)



NOTES:

- Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
- Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

M14.15 (JEDEC MS-012-AB ISSUE C)
14 LEAD NARROW BODY SMALL OUTLINE PLASTIC
PACKAGE

	INC	HES	MILLIM		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
Α	0.0532	0.0688	1.35	1.75	-
A1	0.0040	0.0098	0.10	0.25	-
В	0.013	0.020	0.33	0.51	9
С	0.0075	0.0098	0.19	0.25	-
D	0.3367	0.3444	8.55	8.75	3
Е	0.1497	0.1574	3.80	4.00	4
е	0.050	0.050 BSC		BSC	-
Н	0.2284	0.2440	5.80	6.20	-
h	0.0099	0.0196	0.25	0.50	5
L	0.016	0.050	0.40	1.27	6
N	1	4	1	4	7
α	0°	8º	0°	8º	-

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